



LIC01-SERIES

Application Specific Discretes
A.S.D.™

LIGHT IGNITION CIRCUIT

FEATURES

- HIGH VOLTAGE BREAKOVER DIODE:
 $V_{BO \text{ MIN}} = 195 \text{ or } 215 \text{ V}$
- HIGH HOLDING CURRENT STRUCTURE :
 $I_H > 50 \text{ mA}$
- HIGH PEAK CURRENT PULSE CAPABILITY :
 $I_{TRM} = 50 \text{ A}$
- DIRECT OPERATION ON 220/240 VAC MAINS CIRCUITS.

BENEFITS

- SPACE SAVING THANKS TO MONOLITHIC FUNCTION INTEGRATION
- HIGH RELIABILITY WITH PLANAR TECHNOLOGY

DESCRIPTION

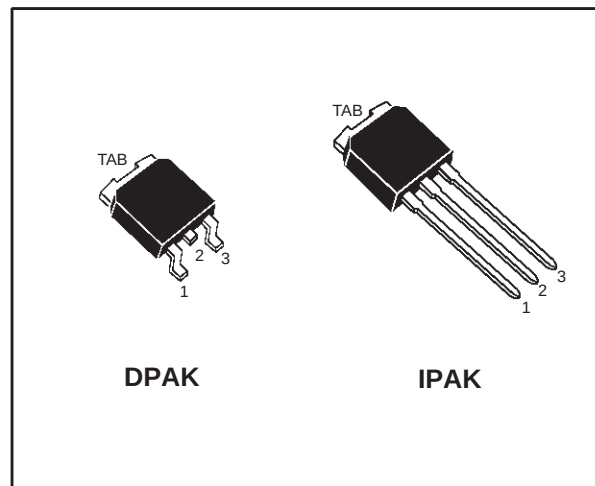
The LIC01 has been especially designed for high voltage pulse generation circuits such as light ignitors for :

- . High pressure sodium lamp
- . Lamp flashing circuit
- . Metal Halid lamp

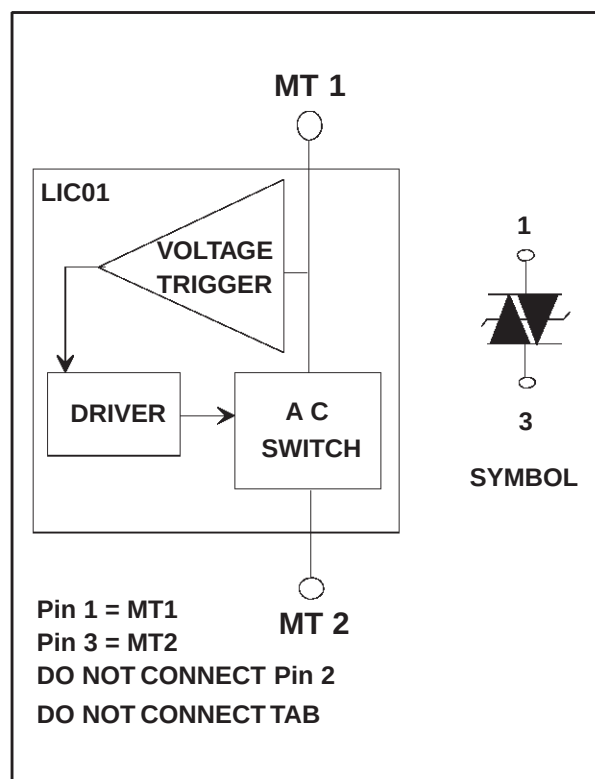
It uses a high performance planar diffused technology device suitable for high surge current operation in rugged environmental conditions.

When the voltage across the device reaches the breakover voltage, it decreases from an off state to low voltage on-state condition. When the current through the circuit drops below the holding current I_H , the device comes back to the off state.

DEVICE TYPE	BREAKDOWN VOLTAGE RANGE
LIC01-195	$V_{BO \text{ min}}: 195\text{V}$ $V_{BO \text{ max}}: 230\text{V}$
LIC01-215	$V_{BO \text{ min}}: 215\text{V}$ $V_{BO \text{ max}}: 255\text{V}$



FUNCTIONAL DIAGRAM

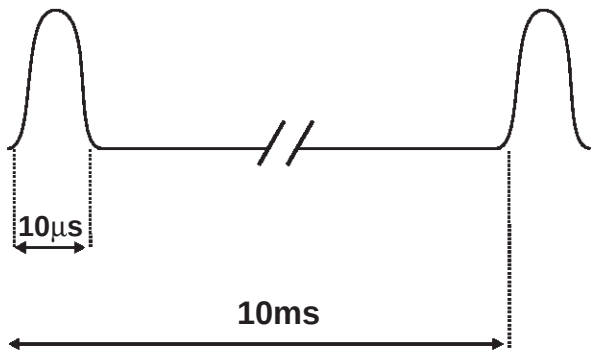


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ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I_{TRM}	Repetitive surge peak on state current	$t_p = 10\mu s$ (note 1)	± 50	A
$I_{T(RMS)}$	RMS on state current	$T_{amb} = 90^{\circ}C$	1.2	A
di/dt	Critical rate of rise on state current		80	A/ μs
V_{DRM} / V_{RRM}	Repetitive peak off state voltage	$T_j = 125^{\circ}C$	180	V
T_{stg}	Storage junction temperature range		- 40 to + 125	$^{\circ}C$
T_j	Operating junction temperature range		-20 to 125	$^{\circ}C$
T_L	Maximum lead temperature for soldering during 10s		260	$^{\circ}C$

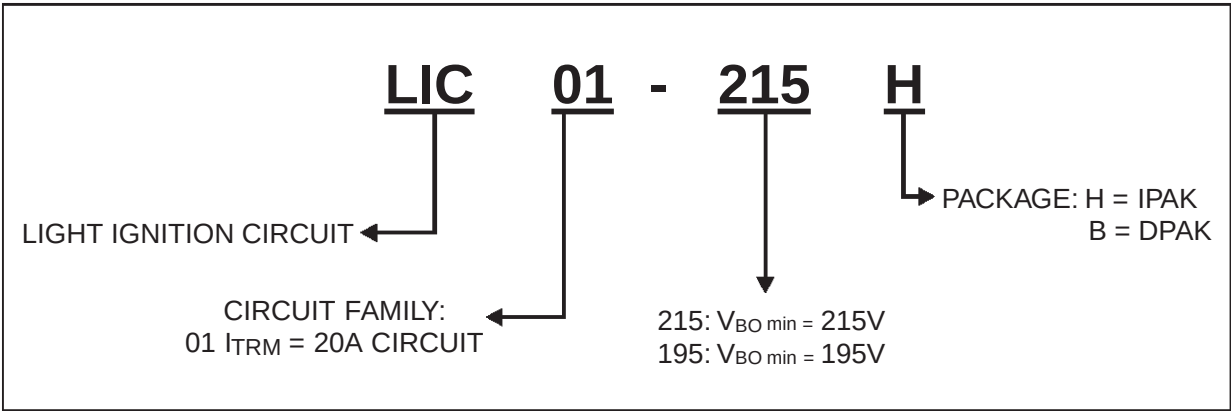
Note 1 : Test current waveform



THERMAL RESISTANCE

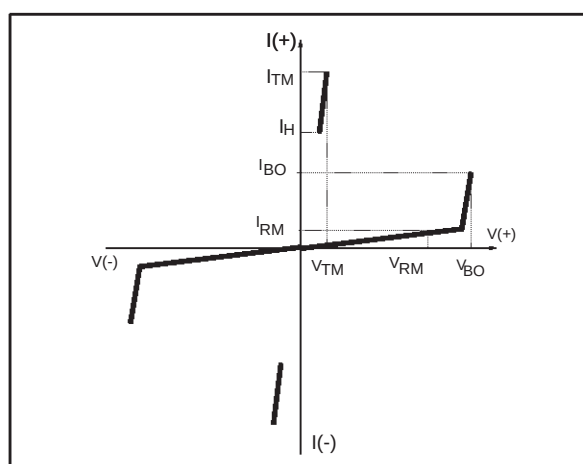
Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to ambient	100	$^{\circ}C/W$
$R_{th(j-c)}$	Junction to case	3.5	$^{\circ}C/W$

ORDERING INFORMATION



ELECTRICAL CHARACTERISTICS

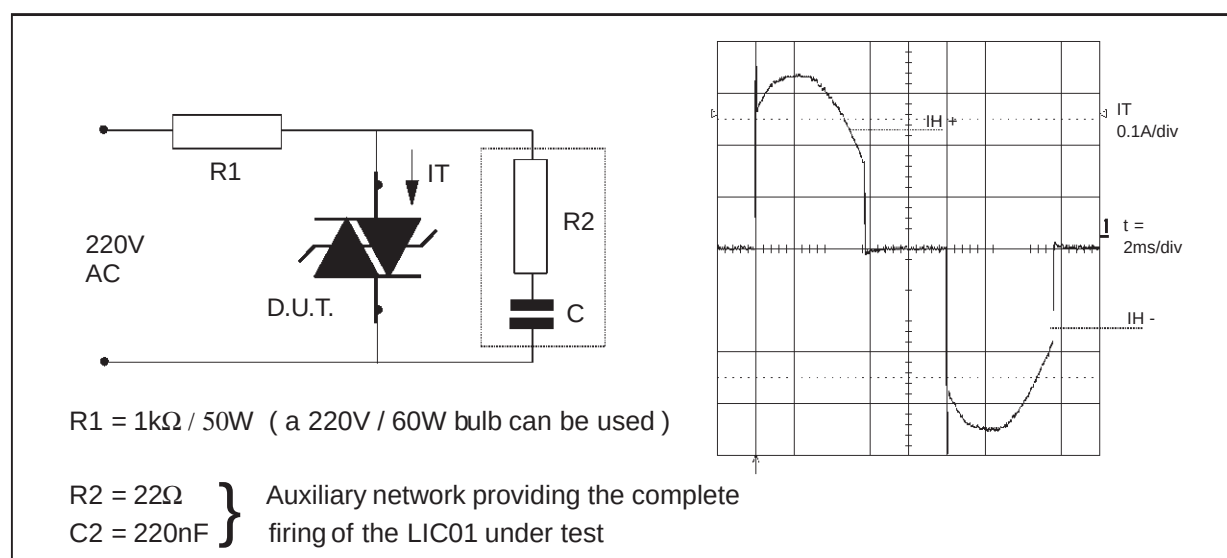
Symbol	Parameters
V_{RM}	Stand-off voltage
V_{TM}	On-state voltage
V_{BO}	Breakover voltage
I_{TM}	On-state current
I_H	Holding current
I_{BO}	Breakover current
I_{RM}	Leakage current



ELECTRICAL PARAMETERS

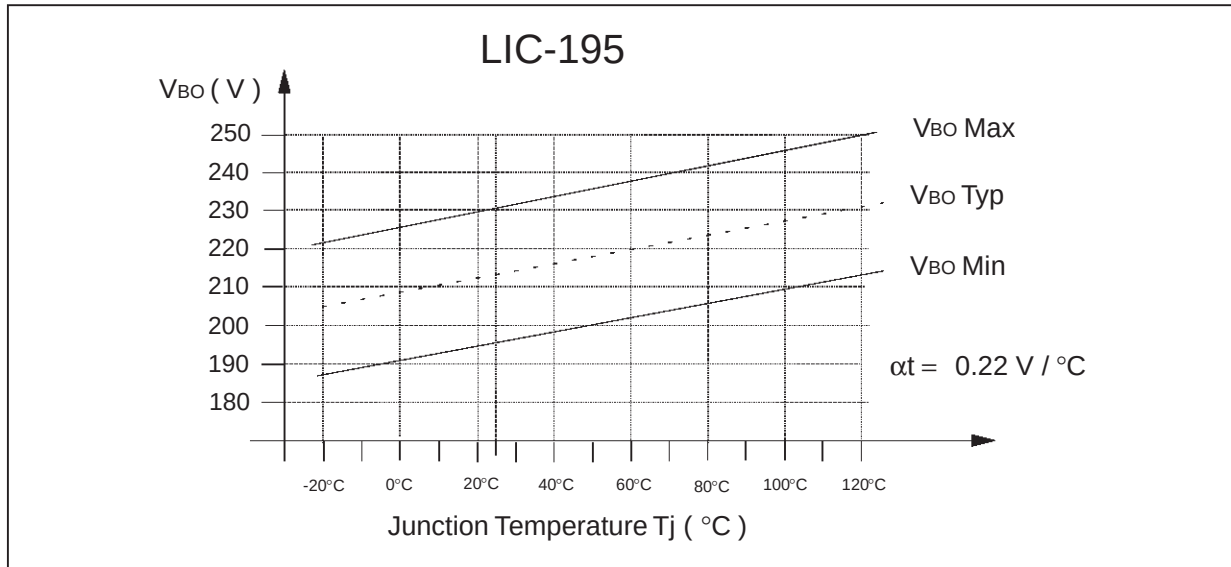
Symbol	Test conditions			Value	Unit	
I _{RM}	V _D = V _{RM} 180V		T _j = 25°C	MAX	5	μA
			T _j = 125°C	MAX	50	μA
V _{BO}	I _{BO}	LIC01-195	T _j = 25°C	MIN	195	V
				MAX	230	
		LIC01-215	T _j = 25°C	MIN	215	V
				MAX	255	
I _{BO}	V _{BO} max.		T _j = 25°C	TYP	200	μA
				MAX	500	
I _H	I _T = 350mA		T _j = 25°C	MIN	50	mA
V _{TM}	I _{TM} = 1A		T _j = 25°C	MAX	5	V

HOLDING CURRENT TEST CIRCUIT

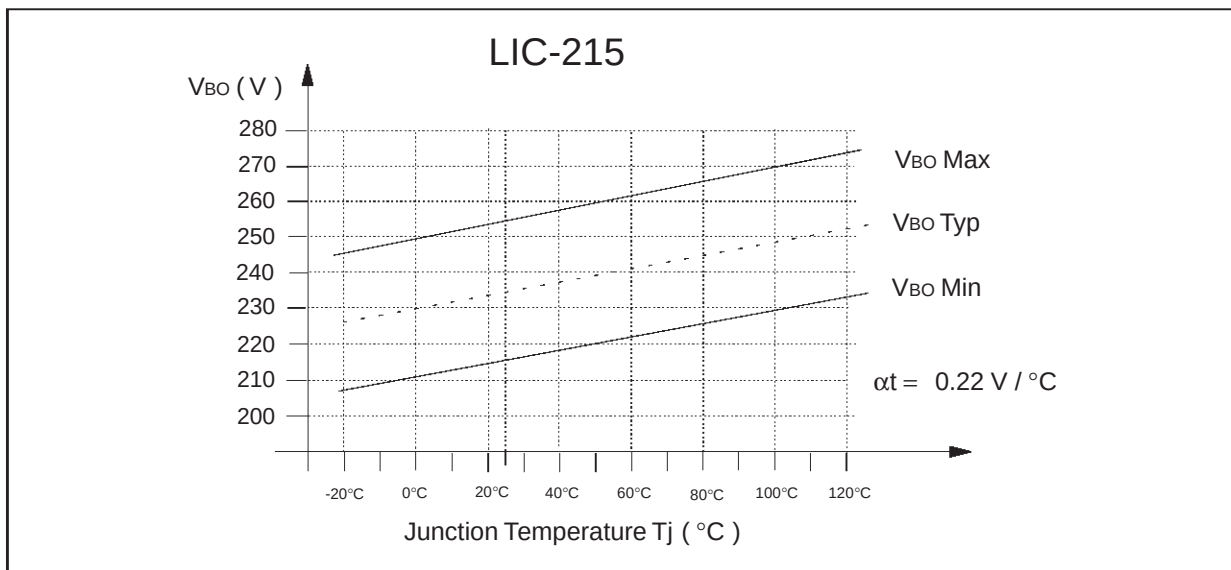


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VARIATION OF V_{BO} VERSUS JUNCTION TEMPERATURE

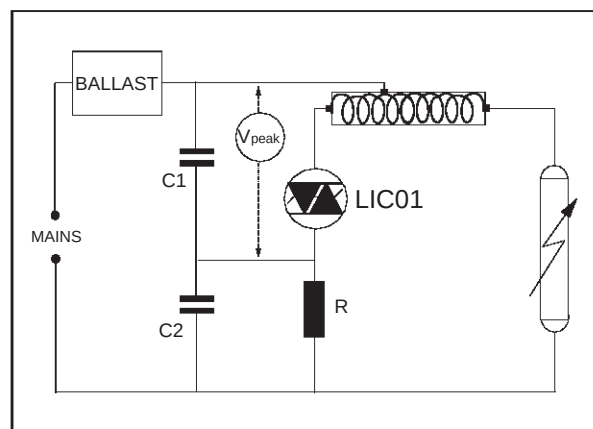


VARIATION OF V_{BO} VERSUS JUNCTION TEMPERATURE



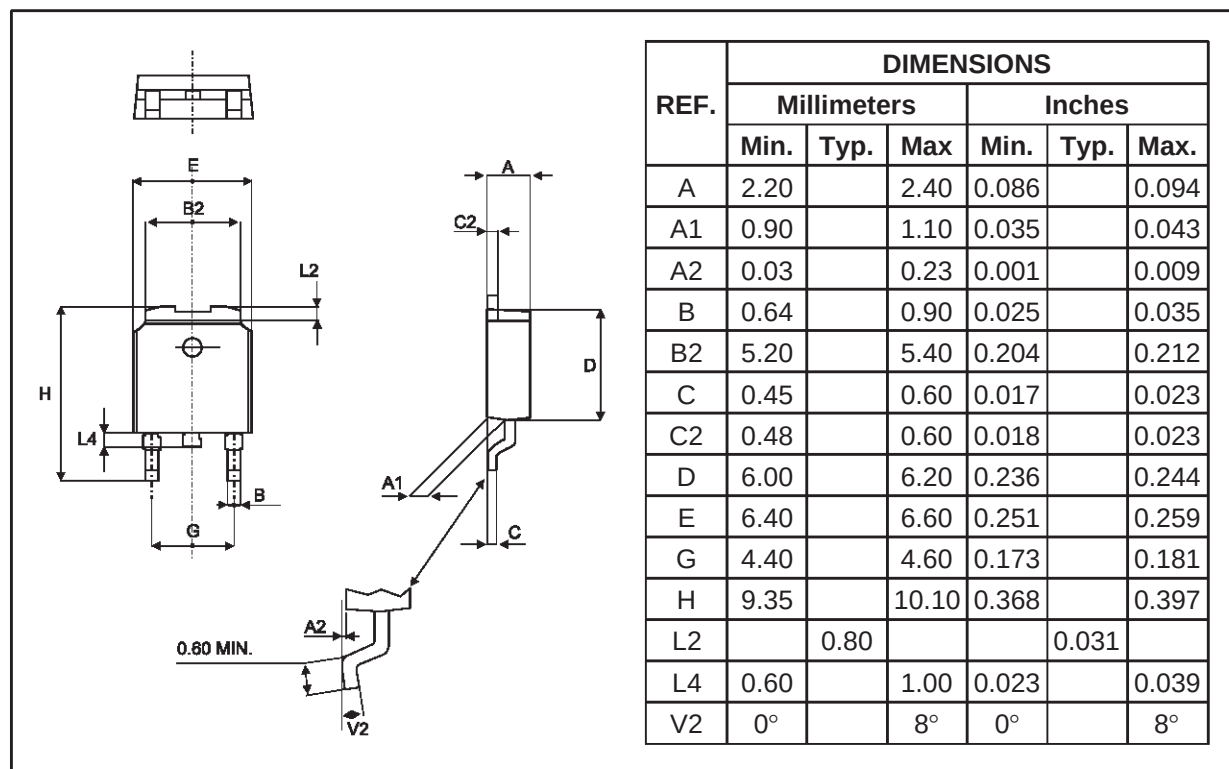
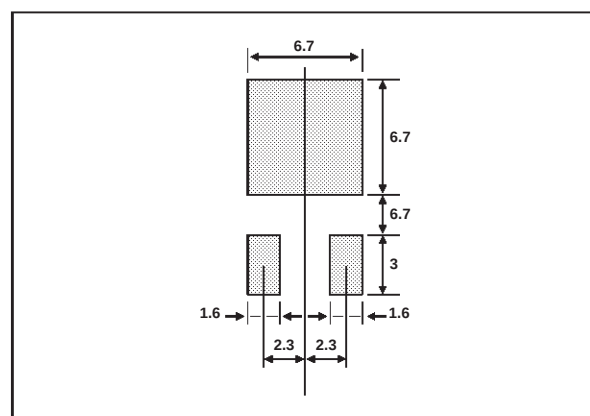
TYPICAL APPLICATION

When the peak voltage across C1 reaches the break over voltage V_{BO} of the LIC01, this device turns on and produces a pulse of current through the primary of the transformer. In turns, the transformer generates high voltage pulses across the lamp.



PACKAGE MECHANICAL DATA

DPAK (Plastic)

**FOOT PRINT DIMENSIONS (in millimeters)**

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PACKAGE MECHANICAL DATA

IPAK (Plastic)

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.7		1.3	0.027		0.051
B	0.64		0.9	0.025		0.035
B2	5.2		5.4	0.204		0.212
B3			0.85			0.033
B5		0.3			0.035	
B6			0.95			0.037
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
H	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1		0.031	0.039
V1		10°			10°	

Type	Marking	Package	Weight	Base qty	Delivery mode
LIC01-xxxH	LIC01-xxxH	IPAK	0.350g	75	Tube
LIC01-xxxB	LIC01-xxxB	DPAK	0.300g	75	Tube

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